

DTC115EM3T5G

DTC115EM3T5G Information

	Transistors - Bipolar (BJT) - Single, Pre-BiasedptionTRANS PREBIAS NPN 260MW SOT723geSOT-723For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



DTC115EM3T5G Specifications

Manufacturer Part Number	DTC115EM3T5G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	SOT-723
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	100k
Resistor - Emitter Base (R2) (Ohms)	100k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 5mA, 10V
Vce Saturation (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	-
Power - Max	260mW
Mounting Type	Surface Mount
Package / Case	SOT-723
Supplier Device Package	SOT-723
	Report errors?

DTC115EM3T5G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DTC115EM3T5G Payment Methods



DTC115EM3T5G Shipping Methods



If you have any question about DTC115EM3T5G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com